

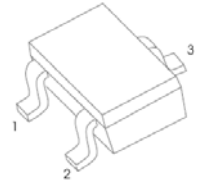


SOT-523 Plastic-Encapsulate MOSFETS

CJ4153 N-Channel 20-V(D-S) MOSFET

$V_{(BR)DSS}$	$R_{DS(on)MAX}$	I_D
20V	570mΩ@4.5V	0.915A
	620mΩ@ 2.5V	
	700mΩ@1.8V	
	9500mΩ@1.5V	

SOT-523



1. GATE
2. SOURCE
3. DRAIN

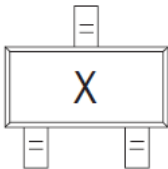
FEATURE

- Low $R_{DS(on)}$ Improving System Efficiency
- Low Threshold Voltage ,1.5V Rated
- ESD Protected Gate
- Pb-Free Packages are Available

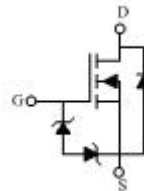
APPLICATION

- Load/Power Switches
- Power Supply Converter Circuits
- Battery Management
- Portables like Cell Phones, PDAs, Digital Cameras, Pagers,etc

MARKING



Equivalent Circuit



Maximum ratings ($T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	20	V
Gate-Source Voltage	V_{GS}	±6	
Continuous Drain Current (note 1)	I_D	0.915	A
Power Dissipation (note 1)	P_D	150	mW
Thermal Resistance from Junction to Ambient (note 1)	$R_{\theta JA}$	833	$^{\circ}C/W$
Operating Junction Temperature	T_J	150	$^{\circ}C$
Storage Temperature	T_{stg}	-55~+150	

MOSFET ELECTRICAL CHARACTERISTICS

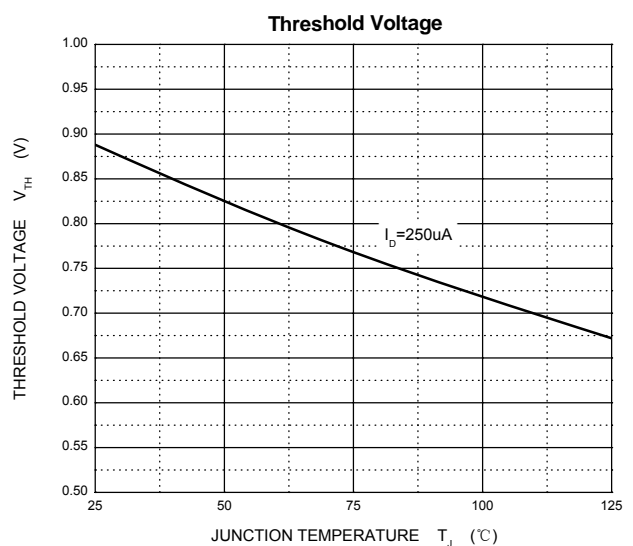
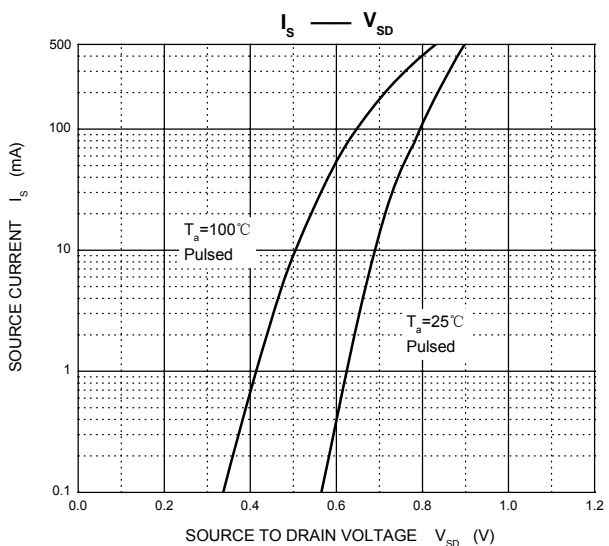
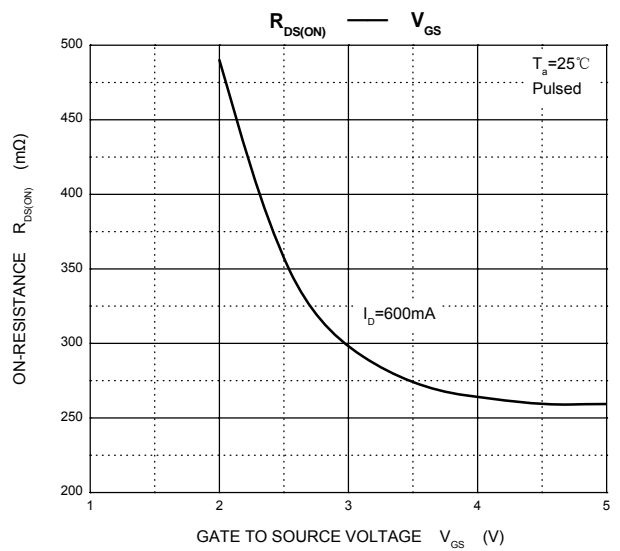
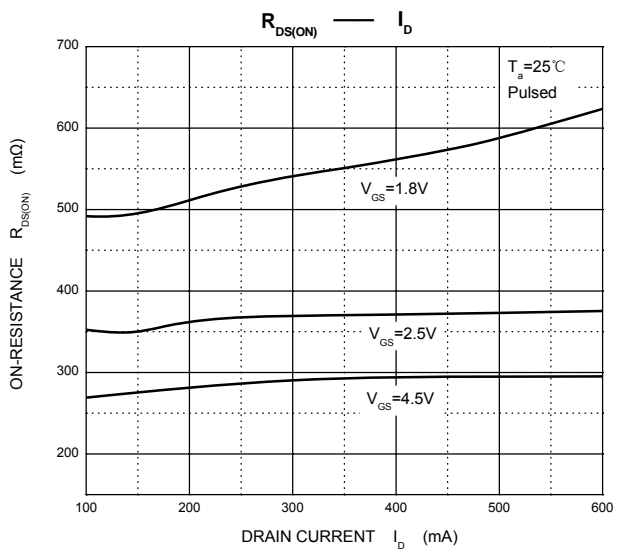
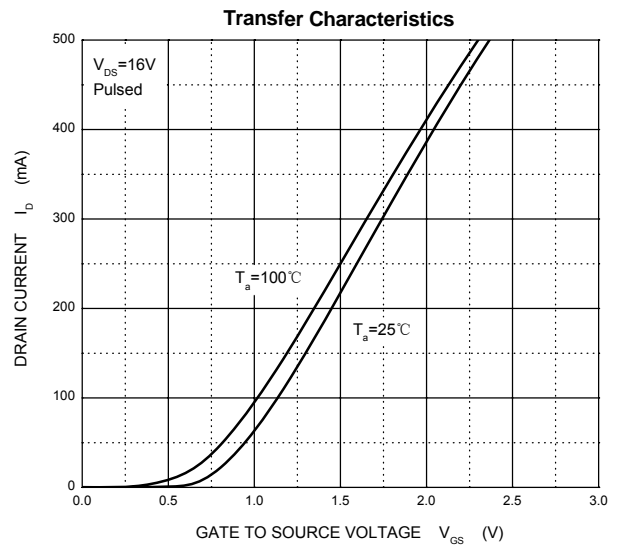
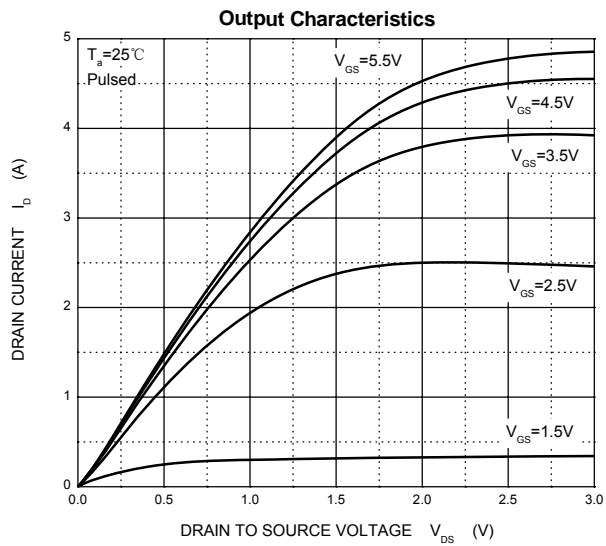
$T_a=25^\circ\text{C}$ unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = 250\mu A$	20			V
Gate-source leakage	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 4.5V$			± 1	μA
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 16V, V_{GS} = 0V$			100	nA
ON CHARACTERISTICS (note 2)						
Gate-source threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250\mu A$	0.45		1.1	V
Drain-source on-state resistance	$R_{DS(on)}$	$V_{GS} = 4.5V, I_D = 600mA$			570	m Ω
		$V_{GS} = 2.5V, I_D = 500mA$			620	
		$V_{GS} = 1.8V, I_D = 350mA$			700	
		$V_{GS} = 1.5V, I_D = 40mA$			9500	
Forward transconductance	g_{fs}	$V_{DS} = 10V, I_D = 400mA$	0.5			S
CHARGES AND CAPACITANCES (note 3)						
Input Capacitance	C_{iss}	$V_{DS} = 16V, V_{GS} = 0V, f = 1MHz$		110		pF
Output Capacitance	C_{oss}			16		
Reverse Transfer Capacitance	C_{rss}			12		
Total Gate Charge	Q_g	$V_{DS} = 10V, V_{GS} = 4.5V, I_D = 200mA$		1.82		nC
Gate-Source Charge	Q_{gs}			0.3		
Gate-Drain Charge	Q_{gd}			0.42		
SWITCHING CHARACTERISTICS (note 3,4)						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = 10V, V_{GS} = 4.5V, R_G = 10\Omega, I_D = 200mA$		3.7		ns
Rise time	t_r			4.4		
Turn-off delay time	$t_{d(off)}$			25		
Fall time	t_f			7.6		
DRAIN-SOURCE DIODE CHARACTERISTICS						
Body diode voltage	V_{SD}	$I_S = 0.2A, V_{GS} = 0V$			1.1	V

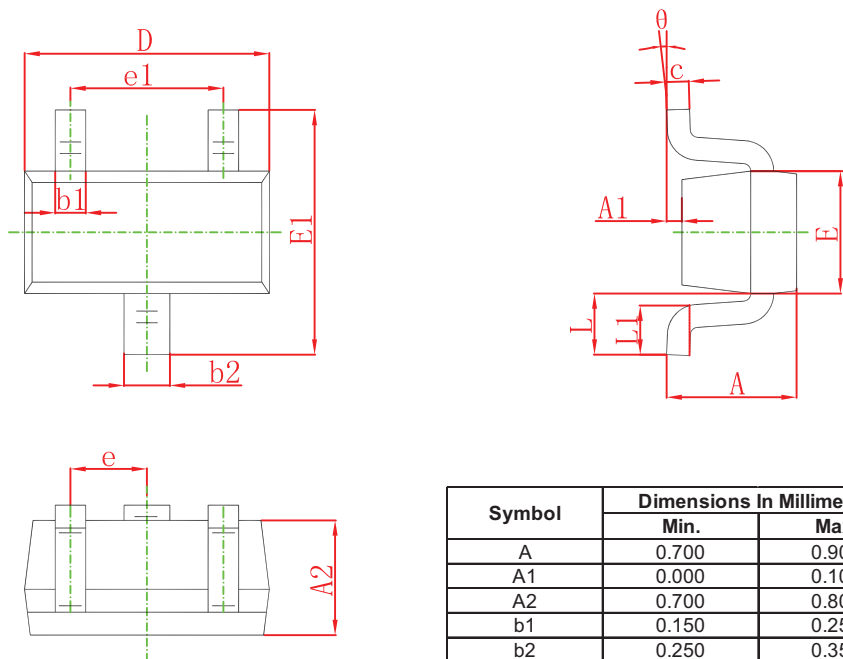
Notes :

1. Surface mounted on FR4 board using 1 in sq pad size.
2. Pulse Test : Pulse width $\leq 300\mu s$, Duty cycle $\leq 2\%$.
3. Guaranteed by design, not subject to production testing.
4. Switching characteristics are independent of operating junction temperatures.

Typical Characteristics

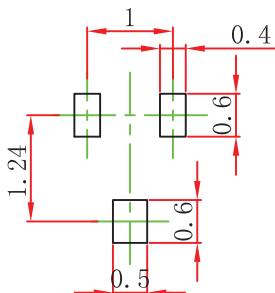


SOT-523 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-523 Suggested Pad Layout



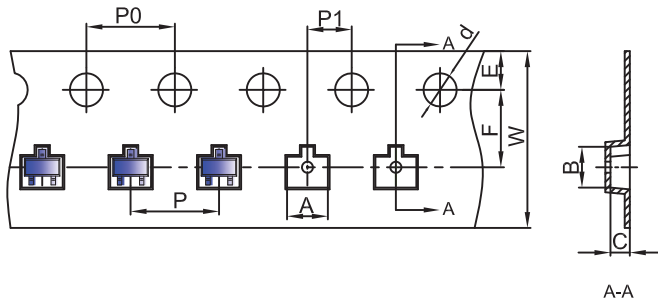
- Note:
1. Controlling dimension: in millimeters.
 2. General tolerance: $\pm 0.05\text{mm}$.
 3. The pad layout is for reference purposes only.

NOTICE

JCET reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to any product herein. JCET does not assume any liability arising out of the application or use of any product described herein.

SOT-523 Tape and Reel

SOT-523 Embossed Carrier Tape



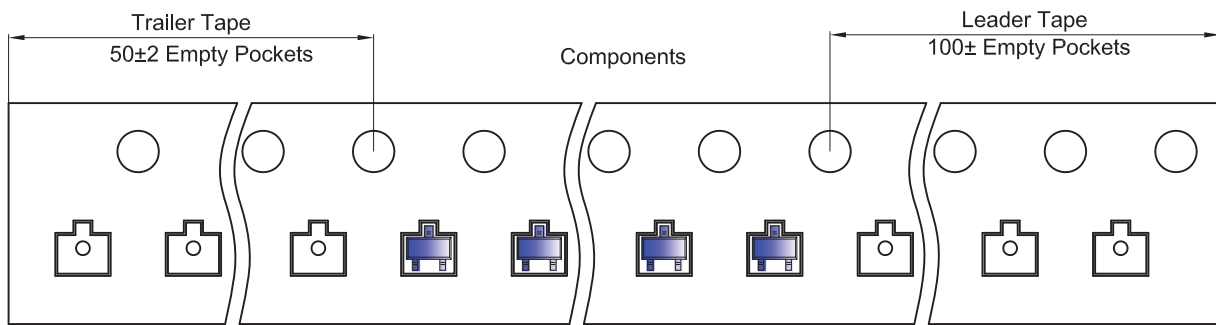
Packaging Description:

SOT-523 parts are shipped in tape. The carrier tape is made from a dissipative (carbon filled) polycarbonate resin. The cover tape is a multilayer film (Heat Activated Adhesive in nature) primarily composed of polyester film, adhesive layer, sealant, and anti-static sprayed agent. These reeled parts in standard option are shipped with 3,000 units per 7" or 17.8cm diameter reel. The reels are clear in color and is made of polystyrene plastic (anti-static coated).

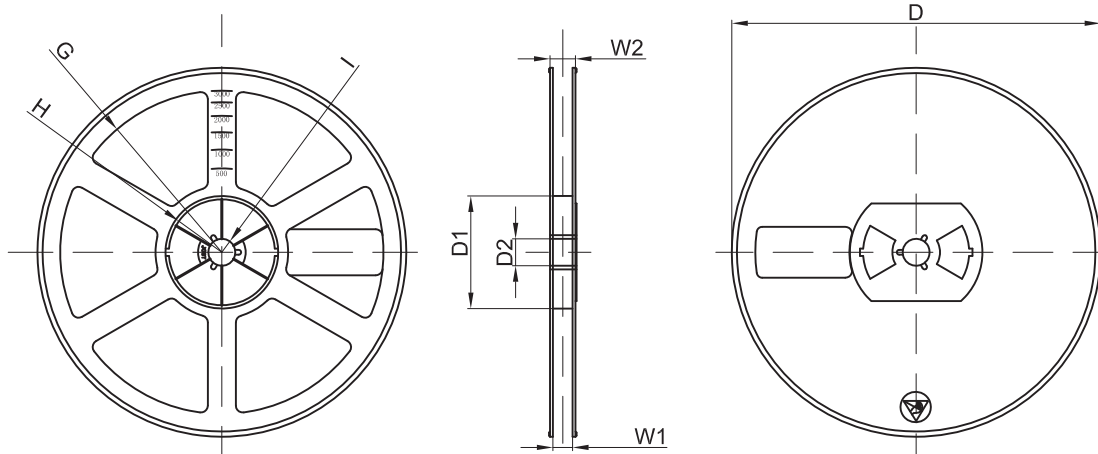
Dimensions are in millimeter

Pkg type	A	B	C	d	E	F	P0	P	P1	W
SOT-523	1.85	1.85	0.875	Ø1.50	1.75	3.50	4.00	4.00	2.00	8.00

SOT-523 Tape Leader and Trailer



SOT-523 Reel



Dimensions are in millimeter

Reel Option	D	D1	D2	G	H	I	W1	W2
7" Dia	Ø178.00	54.40	13.00	R78.00	R25.60	R6.50	9.50	12.30

REEL	Reel Size	Box	Box Size(mm)	Carton	Carton Size(mm)	G.W.(kg)
3000 pcs	7 inch	45,000 pcs	203×203×195	180,000 pcs	438×438×220	

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